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rfmd.com

RF5187

LOW POWER LINEAR AMPLIFIER

RoHS Compliant & Pb-Free Product Package Style: SOIC-8 Slug

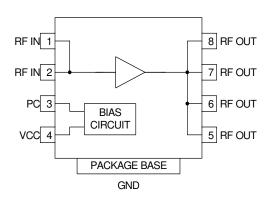


Features

- Single 3V to 6V Supply
- 10dBm to 20dBm Ultra Linear Output Power
- 14dB Gain at 2.14GHz
- Power Down Mode
- 800MHz to 2500MHz Operation

Applications

- 2.14 GHz UMTS Systems
- Digital Communication Systems
- PCS Communication Systems
- Commercial and Consumer Systems



Functional Block Diagram

Product Description

The RF5187 is a highly-linear, low-power amplifier IC. It has been designed for use as the driver RF amplifier in applications such as W-CDMA basestations. The RF5187 requires an input and output matching network and power supply feed line. The device is manufactured on an advanced Gallium Arsenide HBT process, and is packaged in a 8-pin plastic package with a backside ground.

Ordering Information

RF5187 Low Power Linear Amplifier
RF5187PCBA-41X Fully Assembled Evaluation Board

Optimum Technology Matching® Applied

▼ GaAs HBT	☐ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT
☐ GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	
☐ InGaP HBT	☐ SiGe HBT	☐ Si BJT	

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{CC})	-0.5 to +6.5	V_{DC}
Power Control Voltage (V _{PC})	-0.5 to +5V	V
DC Supply Current	300	mA
Input RF Power	+20	dBm
Output Load VSWR	20:1	
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +100	°C



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

Parameter	Specification		Unit	Condition		
raiailletei	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25 °C, V _{CC} =5.0V, I _{CC} =240 mA, Freq=2140 MHz, P _{OUT} =13 dBm	
Frequency Range	800		2500	MHz		
Output Power		13		dBm		
OP1dB		29		dBm		
Small Signal Gain	13		15	dB		
Input VSWR		1.5:1			With external matching network.	
Two-Tone Specification						
Output IP3	41	43	45	dBm	13dBm per tone.	
Power Control						
V _{PC}	2.7	3.1	3.7	V	To obtain 240 mA idle current.	
Power Control "OFF"	0.2	0.5		V	Threshold voltage at device input.	
Power Supply						
Power Supply Voltage	5		6	V		
Supply Current			240	mA		
Power Down Current		2	10	μΑ	V _{PC} =0.2V	

Note: For infrastructure class operation, the maximum allowable current over all operating conditions is 260 mA. This implies the need for an external active bias control network to control I_{CC} over temperature and normal process variation. A recommended active bias control circuit is included in the datasheet.

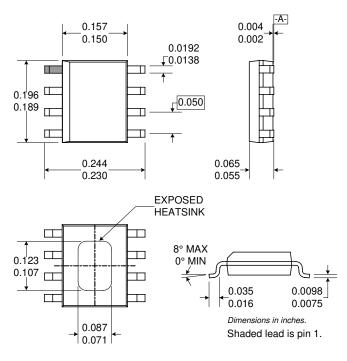
The maximum continuous allowable dissipated power ($I_{CC} * V_{CC} - P_{RF}$) for this part is 1.3 W. For $V_{CC} = 5.0$ V, this implies an I_{CC} limit of 260 mA. A V_{CC} of 6.0 V would have an I_{CC} limit of 215 mA.

A constant I_{CC} of 180 mA to 220 mA provides an excellent combination of high linearity and low power dissipation. Refer to W-CDMA ACP curves at bottom of datasheet.



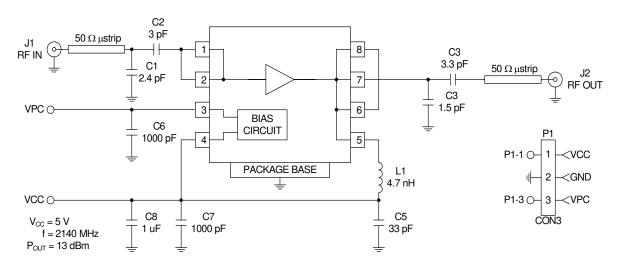
Pin	Function	Description	Interface Schematic		
1	RF IN	RF input. This input is DC-coupled, so an external blocking capacitor is required if this pin is connected to a DC path. An optimum match to 50Ω is obtained by providing an external series capacitor of $2.4\mathrm{pF}$ and then a shunt capacitor of $2.4\mathrm{pF}$. Those values are typical for $2140\mathrm{MHz}$; other values may be required for other frequencies.			
2	RF IN	Same as pin 1.			
3	PC	Power control pin. For obtaining maximum performance, the voltage on this pin can be used to set correct bias level. For low power linear applications, it is recommended that a constant bias control loop be used (see datasheet evaluation board schematic). A voltage of 0.5V or less at V _{PC} brings the part into Power Down State.			
4	VCC	Power supply pin for the bias circuits. External low frequency bypass capacitors should be connected if no other low frequency decoupling is nearby.			
5	RF OUT	RF output and bias for the output stage. The power supply for the output transistor needs to be supplied to this pin. This can be done through a quarter-wavelength microstrip line that is RF-grounded at the other end, or through an RF inductor that supports the required DC currents. Optimum load impedance is achieved by providing a shunt capacitor of 1.8 pF and a series capacitor of 3.3 pF. Those values are typical for 2140 MHz; other values may be required for other frequencies. Since there are several output pins available (which are internally connected), one pin can be used for connecting the bias, another for connecting a (third) harmonic trap filter, and the other pins for the RF output.			
6	RF OUT	Same as pin 5.			
7	RF OUT	Same as pin 5.			
8	RF OUT	Same as pin 5.			
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path (i.e., vias under the device may be required).			

Package Drawing

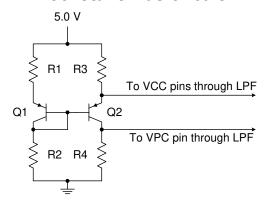




Evaluation Board Schematic 2140 MHz Operation



Constant Bias Circuit

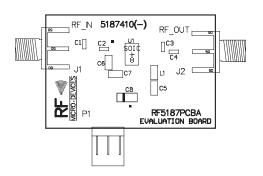


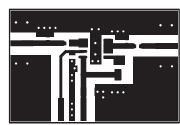
Bias Point	R1	R2	R3	R4
mA	Ω	Ω	Ω	Ω
100	120	1200	3.6	820
120	120	1200	3.0	820
150	120	1200	2.5	820
180	120	1200	2.0	820
200	120	1200	1.8	820
220	120	1200	1.7	820
240	120	1200	1.6	820

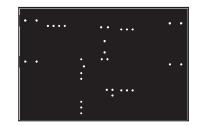


Evaluation Board Layout Board Size 1.5" x 1.0"

Board Thickness 0.031", Board Material FR-4

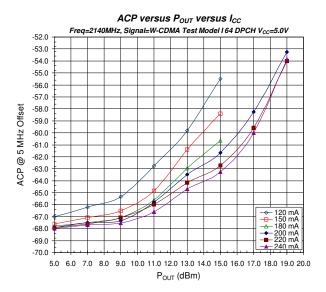






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RoHS* Banned Material Content

RoHS Compliant: Yes
Package total weight in grams (g): 0.091
Compliance Date Code: 0523
Bill of Materials Revision: Pb Free Category: e3

Bill of Materials		Parts Per Million (PPM)					
	Pb	Cd	Hg	Cr VI	PBB	PBDE	
Die	0	0	0	0	0	0	
Molding Compound	0	0	0	0	0	0	
Lead Frame	0	0	0	0	0	0	
Die Attach Epoxy	0	0	0	0	0	0	
Wire	0	0	0	0	0	0	
Solder Plating	0	0	0	0	0	0	

This RoHS banned material content declaration was prepared solely on information, including analytical data, provided to RFMD by its suppliers, and applies to the Bill of Materials (BOM) revision noted above.

^{*} DIRECTIVE 2002/95/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

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